

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicants: T. KOBAYASHI

Application No.: Rule 1.53(b) Continuation of U.S. Patent Application  
Serial No. 09/811,444, filed March 20, 2001

Filed: On even date herewith

For: NONVOLATILE SEMICONDUCTOR MEMORY DEVICE  
WITH IMPROVED GATE OXIDE FILM ARRANGEMENT  
(As Amended)

Art Group of Parent: 2826

Examiner of Parent: K. Quinto

**PRELIMINARY AMENDMENT**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

October 15, 2003

Sir:

Prior to examination, please amend the above-identified application as listed below and as set forth on the following pages:

**Amendments to the Specification and Title**

**Amendments to the claims and**

**Remarks are included after the amendments.**